

HIP4080

80V/2.5A Peak, High Frequency Full Bridge FET Driver

December 1996

Features

- Drives N-Channel FET Full Bridge Including High Side Chop Capability
- Bootstrap Supply Max Voltage to 95V_{DC}
- Drives 1000pF Load at 1MHz in Free Air at 50°C with Rise and Fall Times of 10ns (Typ)
- User-Programmable Dead Time
- Charge-Pump and Bootstrap Maintain Upper Bias Supplies
- · DIS (Disable) Pin Pulls Gates Low
- Input Logic Thresholds Compatible with 5V to 15V Logic Levels
- Very Low Power Consumption

Applications

- Medium/Large Voice Coil Motors
- Full Bridge Power Supplies
- Class D Audio Power Amplifiers
- High Performance Motor Controls
- Noise Cancellation Systems
- Battery Powered Vehicles
- Peripherals
- U.P.S.

Description

The HIP4080 is a high frequency, medium voltage Full Bridge N-Channel FET driver IC, available in 20 lead plastic SOIC and DIP packages. The HIP4080 includes an input comparator, used to facilitate the "hysteresis" and PWM modes of operation. Its HEN (high enable) lead can force current to freewheel in the bottom two external power MOSFETs, maintaining the upper power MOSFETs off. Since it can switch at frequencies up to 1MHz, the HIP4080 is well suited for driving Voice Coil Motors, switching amplifiers in class D high-frequency switching audio amplifiers and power supplies.

HIP4080 can also drive medium voltage brush motors, and two HIP4080s can be used to drive high performance stepper motors, since the short minimum "on-time" can provide fine micro-stepping capability.

Short propagation delays of approximately 55ns maximizes control loop crossover frequencies and dead-times which can be adjusted to near zero to minimize distortion, resulting in precise control of the driven load.

The similar HIP4081 IC allows independent control of all 4 FETs in an Full Bridge configuration.

See also, Application Note AN9324 for the HIP4080.

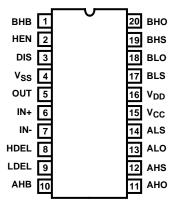
Similar part, HIP4080A, includes under voltage circuitry which doesn't require the circuitry shown in Figure 30 of this data sheet.

Ordering Information

| PART NUMBER | TEMP. RANGE (^o C) | PACKAGE | PKG. NO. |
|----------------|----------------------------------|--------------|-------------|
| HIP4080IP | -40 to 85 | 20 Lead PDIP | E20.3 |
| HIP4080IB | -40 to 85 | 20 Lead SOIC | M20.3 |

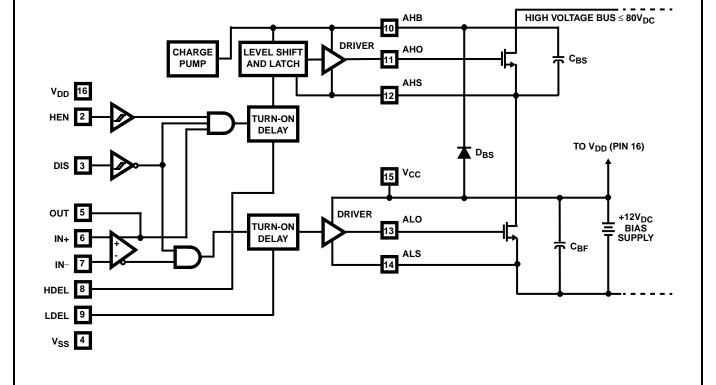
Pinout

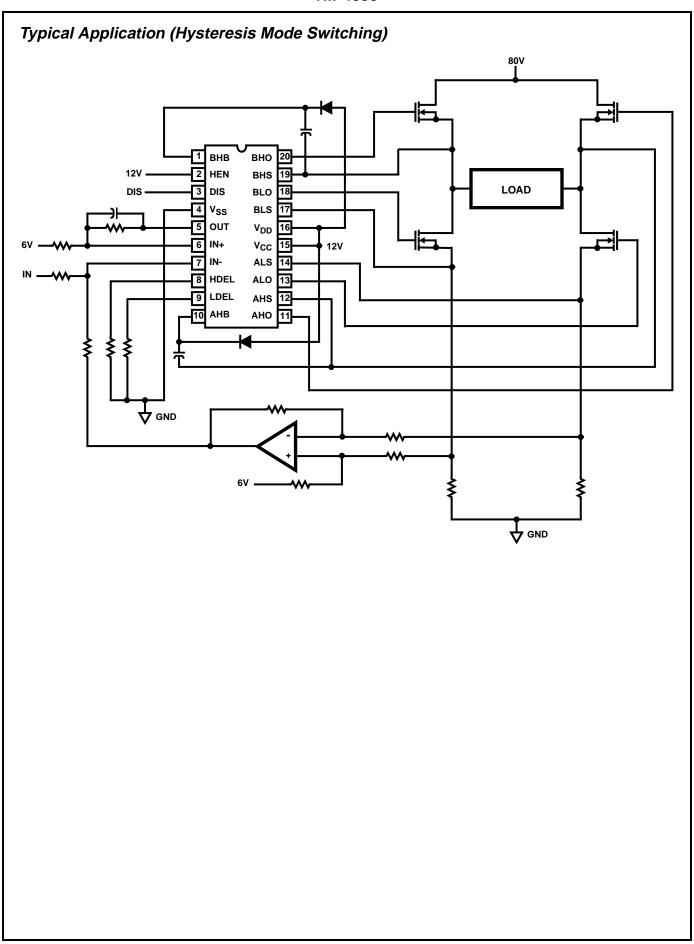
HIP4080 (PDIP, SOIC) TOP VIEW



Application Block Diagram 80V 12V вно BHS LOAD HEN BLO DIS HIP4080 IN+ ALO AHS IN-AHO GND GND

Functional Block Diagram (1/2 HIP4080)





HIP4080

Absolute Maximum Ratings

Supply Voltage, V_{DD} and V_{CC} -0.3V to 16V Logic I/O Voltages -0.3V to V_{DD} +0.3V Voltage on AHS, BHS....-6.0V (Transient) to 80V (25°C to 125°C) Voltage on AHS, BHS....-6.0V (Transient) to 70V (-55°C to 125°C Voltage on ALS, BLS-2.0V (Transient) to +2.0V (Transient) Voltage on AHB, BHBV_{AHS, BHS} -0.3V to V_{AHS, BHS} +16VVoltage on Voltage on ALO, BLO V_{ALS, BLS} -0.3V to V_{CC} +0.3V Voltage on AHO, BHO V_{AHS, BHS} -0.3V to V_{AHB, BHB} +0.3V Input Current, HDEL and LDEL -5mA to 0mA Phase Slew Rate20V/ns NOTE: All Voltages relative to pin 4, V_{SS}, unless otherwise specified.

Thermal Information

| Thermal Resistance (Typical, Note 1) | θ_{JA} (°C/W) |
|--------------------------------------|----------------------|
| SOIC Package | 85 |
| PDIP Package | 75 |
| Maximum Power Dissipation at 85°C | |
| SOIC Package | 470mW |
| DIP Package | |
| Storage Temperature Range6 | 5°C to 150°C |
| Operating Max. Junction Temperature | 125 ⁰ C |
| Lead Temperature (Soldering 10s) | 300°C |
| (SOIC - Lead Tips Only) | |
| | |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Operating Conditions

| Supply Voltage, V _{DD} and V _{CC} +8V to +15V | Input Current, HDEL and LDEL500μA to -50μA |
|---|---|
| Voltage on ALS, BLS1.0V to +1.0V | Operating Ambient Temperature Range40°C to 85°C |
| Voltage on AHB, BHB V _{AHS, BHS} +5V to V _{AHS, BHS} +15V | |

 $\textbf{Electrical Specifications} \qquad V_{DD} = V_{CC} = V_{AHB} = V_{BHB} = 12V, \ V_{SS} = V_{ALS} = V_{BLS} = V_{AHS} = V_{BHS} = 0V, \ R_{HDEL} = R_{LDEL} = 100K, \ R_{HDEL} = R_{LDEL} = 1$ and T_A = 25°C, Unless Otherwise Specified

| | | | Т | ່ງ = 25 ⁰ | С | T _J = - 40°C TO 125°C | | |
|--|-------------------------------------|---|-------------------------|----------------------|-------------------------|-------------------------------------|-------------------------|-------|
| PARAMETERS | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | MIN | MAX | UNITS |
| SUPPLY CURRENTS AND CHARGE | PUMPS | | | | | | | |
| V _{DD} Quiescent Current | I_{DD} | IN- = 2.5V, Other Inputs = 0V | 8 | 10.5 | 13 | 7 | 14 | mA |
| V _{DD} Operating Current | I _{DDO} | Outputs switching f = 500kHz | 9 | 11 | 14 | 8 | 15 | mA |
| V _{CC} Quiescent Current | I _{CC} | IN- = 2.5V, Other Inputs = 0V, $I_{ALO} = I_{BLO} = 0$ | - | 25 | 80 | - | 100 | μΑ |
| V _{CC} Operating Current | Icco | f = 500kHz, No Load | 1 | 1.5 | 2.0 | 0.8 | 3 | mA |
| AHB, BHB Quiescent Current - Qpump Output Current | І _{АНВ} , І _{ВНВ} | IN- = 2.5V, Other Inputs = 0V, I _{AHO} = I _{BHO} = 0, V _{DD} = V _{CC} = V _{AHB} = V _{BHB} = 10V | | -30 | -15 | -60 | -10 | μА |
| AHB, BHB Operating Current | Ганвовнво | f = 500kHz, No Load | 0.5 | 0.9 | 1.3 | 0.4 | 1.7 | mA |
| AHS, BHS, AHB, BHB Leakage Current | I _{HLK} | $V_{AHS} = V_{BHS} = V_{AHB} = V_{BHB} = 95V$ | - | 0.02 | 1.0 | - | 10 | μΑ |
| AHB-AHS, BHB-BHS Qpump Output Voltage VAHB-VAHS VBHB-VBHS | | $I_{AHB} = I_{AHB} = 0$, No Load | 11.5 | 12.6 | 14.0 | 10.5 | 14.5 | V |
| INPUT COMPARATOR PINS: IN+, IN | I-, OUT | | | | | | | |
| Offset Voltage | Vos | Over Common Mode Voltage Range | -10 | 0 | +10 | -15 | +15 | mV |
| Input Bias Current | I _{IB} | | 0 | 0.5 | 2 | 0 | 4 | μΑ |
| Input Offset Current | Ios | | -1 | 0 | +1 | -2 | +2 | μΑ |
| Input Common Mode Voltage Range | CMVR | | 1 | - | V _{DD} -1.5 | 1 | V _{DD} -1.5 | V |
| Voltage Gain | AVOL | | 10 | 25 | - | 10 | - | V/mV |
| OUT High Level Output Voltage | V _{OH} | IN+ > IN-, I _{OH} = -300μA | V _{DD} -0.4 | - | - | V _{DD} - 0.5 | - | V |
| OUT Low Level Output Voltage | V_{OL} | IN+ < IN-, I _{OL} = 300μA | - | - | 0.3 | - | 0.4 | V |
| High Level Output Current | I _{OH} | V _{OUT} = 6V | -9 | -7 | -4 | -11 | -2 | mA |
| Low Level Output Current | I _{OL} | V _{OUT} = 6V | 8 | 10 | 12 | 5 | 14 | mA |
| INPUT PINS: DIS | | | _ | _ | | | _ | |
| Low Level Input Voltage | V_{IL} | Full Operating Conditions | - | - | 1.0 | - | 0.8 | V |
| High Level Input Voltage | V_{IH} | Full Operating Conditions | 2.5 | - | - | 2.7 | - | V |
| Input Voltage Hysteresis | | | - | 35 | - | - | - | mV |

Electrical Specifications $V_{DD} = V_{CC} = V_{AHB} = V_{BHB} = 12V$, $V_{SS} = V_{ALS} = V_{BLS} = V_{AHS} = 0V$, $V_{BHS} = 0V$, $V_{BHS} = 100V$, and $V_{AHS} = 100V$, $V_{AHS} = 100V$, and $V_{AHS} = 100V$, $V_{AHS} = 10$

| | | | T _J = 25 ^o C | | С | T _J = - 40 ^o C TO 125 ^o C | | |
|-------------------------------|-----------------------------------|---|------------------------------------|------|------|---|------|-------|
| PARAMETERS | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | MIN | MAX | UNITS |
| Low Level Input Current | I _Ι L | V _{IN} = 0V, Full Operating Conditions | -130 | -100 | -75 | -135 | -65 | μΑ |
| High Level Input Current | I _{IH} | V _{IN} = 5V, Full Operating Conditions | -1 | - | +1 | -10 | +10 | μΑ |
| INPUT PINS: HEN | | | | | | | | |
| Low Level Input Voltage | V_{IL} | Full Operating Conditions | - | - | 1.0 | - | 8.0 | V |
| High Level Input Voltage | V_{IH} | Full Operating Conditions | 2.5 | - | - | 2.7 | - | V |
| Input Voltage Hysteresis | | | - | 35 | - | - | - | mV |
| Low Level Input Current | Ι _Ι L | V _{IN} = 0V, Full Operating Conditions | -260 | -200 | -150 | -270 | -130 | μΑ |
| High Level Input Current | I _{IH} | V _{IN} = 5V, Full Operating Conditions | -1 | - | +1 | -10 | +10 | μΑ |
| TURN-ON DELAY PINS: LDEL AND | HDEL | | | | | | | |
| LDEL, HDEL Voltage | $V_{HDEL,}V$ | $I_{HDEL} = I_{LDEL} = -100\mu A$ | 4.9 | 5.1 | 5.3 | 4.8 | 5.4 | V |
| GATE DRIVER OUTPUT PINS: ALO, | BLO, AHO, | AND BHO | | | | | | |
| Low Level Output Voltage | V_{OL} | I _{OUT} = 100mA | .70 | 0.85 | 1.0 | 0.5 | 1.1 | V |
| High Level Output Voltage | V _{CC} - V _{OH} | I _{OUT} = -100mA | 0.8 | 0.95 | 1.1 | 0.5 | 1.2 | V |
| Peak Pull-up Current | I _O + | V _{OUT} = 0V | 1.7 | 2.6 | 3.8 | 1.4 | 4.1 | Α |
| Peak Pull-down Current | I _O - | V _{OUT} = 12V | 1.7 | 2.4 | 3.3 | 1.3 | 3.6 | Α |

Switching Specifications $V_{DD} = V_{CC} = V_{AHB} = V_{BHB} = 12V$, $V_{SS} = V_{ALS} = V_{BLS} = V_{AHS} = 0V$, $V_{BHS} = 0V$, $V_{BHS} = 10V$, $V_{BHS} =$

| | | | T _J = 25 ^o C | | .c | T _J = - 40 ^o C TO 125 ^o C | | |
|--|-----------------------|-----------------------------|------------------------------------|-----|-----|---|-----|-------|
| PARAMETERS | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | MIN | MAX | UNITS |
| Lower Turn-off Propagation Delay (IN+/IN- to ALO/BLO) | T _{LPHL} | | - | 40 | 70 | - | 90 | ns |
| Upper Turn-off Propagation Delay (IN+/IN- to AHO/BHO) | T _{HPHL} | | - | 50 | 80 | - | 110 | ns |
| Lower Turn-on Propagation Delay (IN+/IN- to ALO/BLO) | T _{LPLH} | $R_{HDEL} = R_{LDEL} = 10K$ | - | 45 | 70 | - | 90 | ns |
| Upper Turn-on Propagation Delay (IN+/IN- to AHO/BHO) | T _{HPLH} | $R_{HDEL} = R_{LDEL} = 10K$ | - | 70 | 110 | - | 140 | ns |
| Rise Time | T _r | | - | 10 | 25 | - | 35 | ns |
| Fall Time | T _f | | - | 10 | 25 | - | 35 | ns |
| Turn-on Input Pulse Width | T _{PWIN-ON} | $R_{HDEL} = R_{LDEL} = 10K$ | 50 | - | - | 50 | - | ns |
| Turn-off Input Pulse Width | T _{PWIN-OFF} | $R_{HDEL} = R_{LDEL} = 10K$ | 40 | - | - | 40 | - | ns |
| Disable Turn-off Propagation Delay (DIS - Lower Outputs) | T _{DISLOW} | | - | 45 | 75 | - | 95 | ns |
| Disable Turn-off Propagation Delay (DIS - Upper Outputs) | T _{DISHIGH} | | - | 55 | 85 | - | 105 | ns |
| Disable to Lower Turn-on Propagation Delay (DIS - ALO and BLO) | T _{DLPLH} | | - | 35 | 70 | - | 90 | ns |
| Refresh Pulse Width (ALO and BLO) | T _{REF-PW} | | 160 | 260 | 380 | 140 | 420 | ns |
| Disable to Upper Enable (DIS - AHO and BHO) | T _{UEN} | | - | 335 | 500 | - | 550 | ns |
| HEN-AHO, BHO Turn-off, Propagation Delay | T _{HEN-PHL} | $R_{HDEL} = R_{LDEL} = 10K$ | - | 35 | 70 | - | 90 | ns |
| HEN-AHO, BHO Turn-on, Propagation Delay | T _{HEN-PLH} | $R_{HDEL} = R_{LDEL} = 10K$ | - | 60 | 90 | - | 110 | ns |

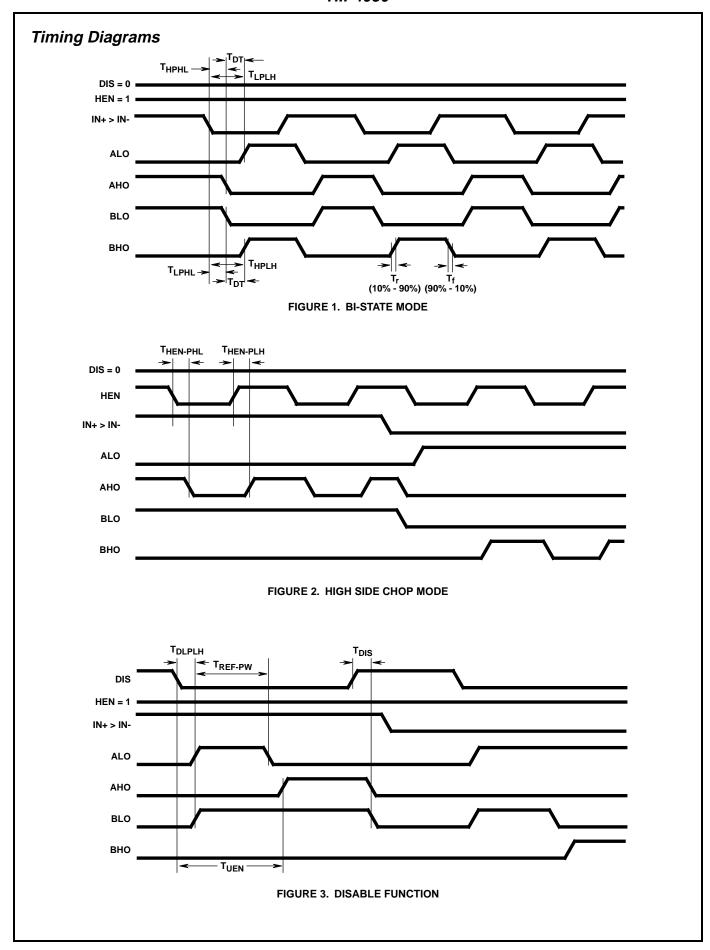
TRUTH TABLE

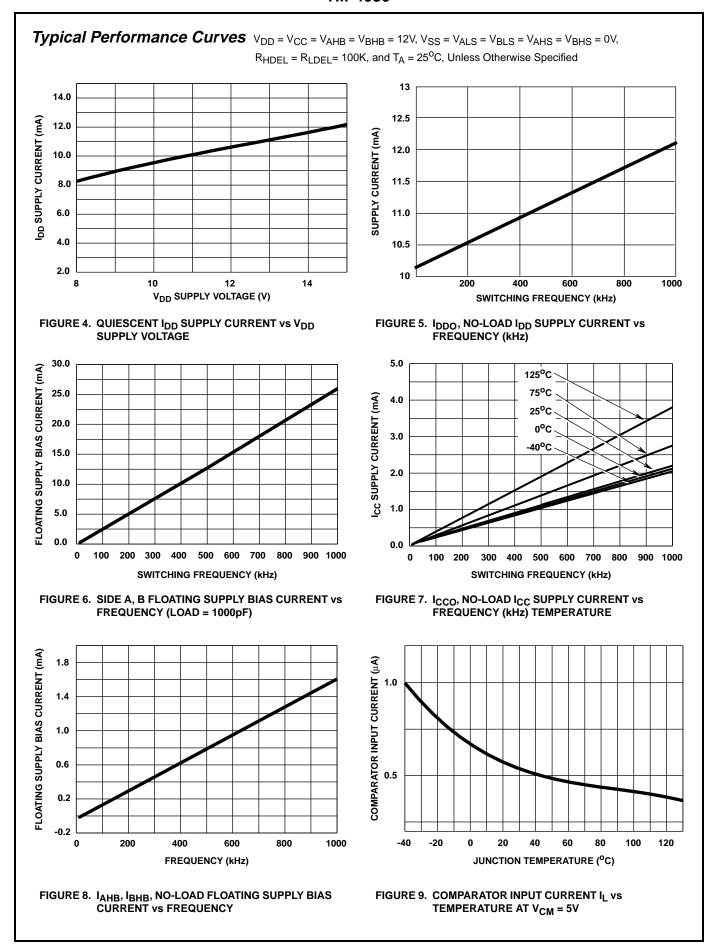
| | INPUT | | OUTPUT | | | | | |
|-----------|-------|-----|---------------|---|---|---|--|--|
| IN+ > IN- | HEN | DIS | ALO AHO BLO E | | | | | |
| X | X | 1 | 0 | 0 | 0 | 0 | | |
| 1 | 1 | 0 | 0 | 1 | 1 | 0 | | |
| 0 | 1 | 0 | 1 | 0 | 0 | 1 | | |
| 1 | 0 | 0 | 0 | 0 | 1 | 0 | | |
| 0 | 0 | 0 | 1 | 0 | 0 | 0 | | |

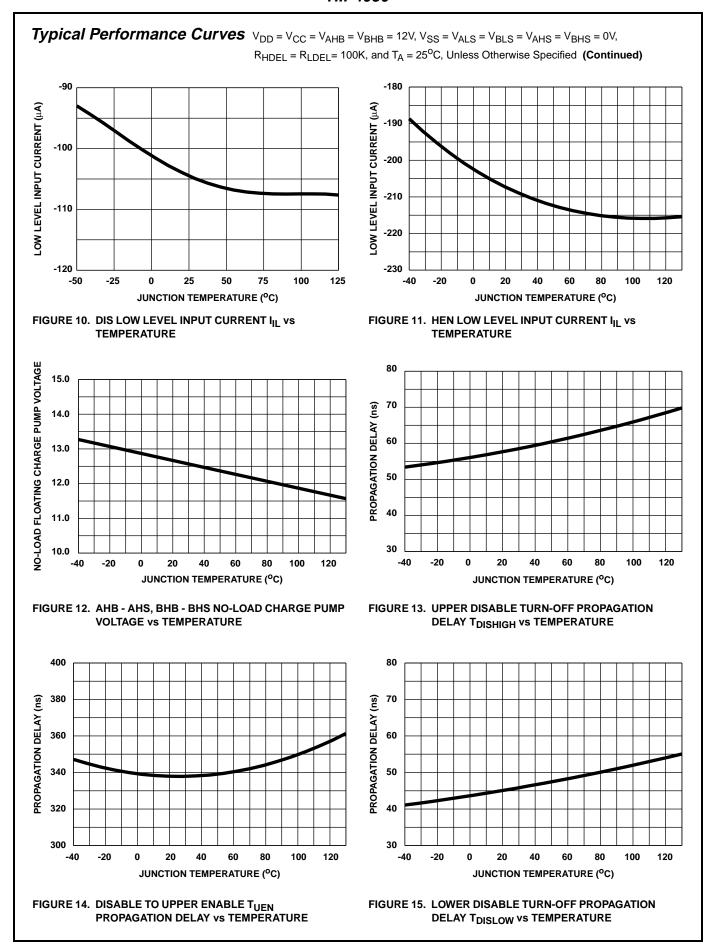
HIP4080

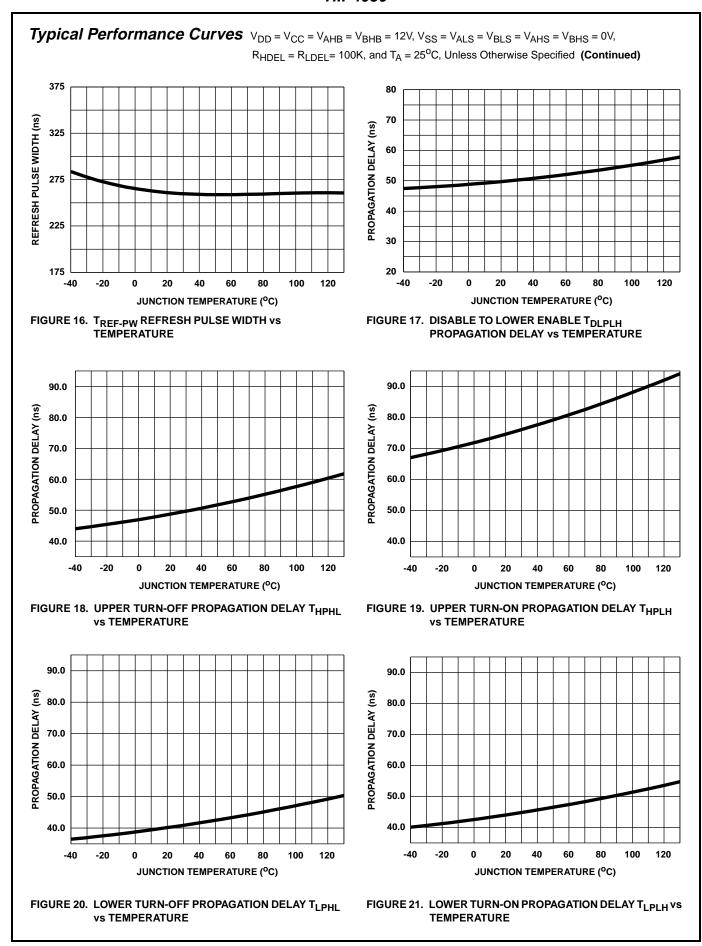
Pin Descriptions

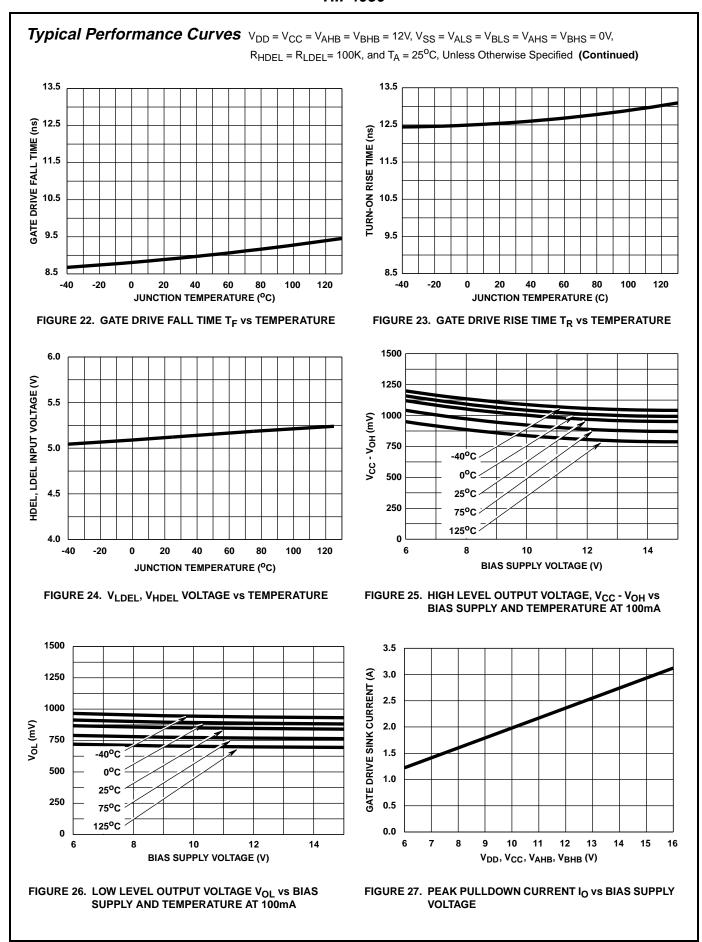
| PIN NUMBER | SYMBOL | DESCRIPTION |
|---------------|-----------------|---|
| 1 | ВНВ | B High-side Bootstrap supply. External bootstrap diode and capacitor are required. Connect cathode of bootstrap diode and positive side of bootstrap capacitor to this pin. Internal charge pump supplies 30μA out of this pin to maintain bootstrap supply. Internal circuitry clamps the bootstrap supply to approximately 12.8V. |
| 2 | HEN | High-side Enable input. Logic level input that when low overrides IN+/IN- (Pins 6 and 7) to put AHO and BHO drivers (Pins 11 and 20) in low output state. When HEN is high AHO and BHO are controlled by IN+/IN- inputs The pin can be driven by signal levels of 0V to 15V (no greater than V_{DD}). An internal 100 μ A pull-up to V_{DD} will hold HEN high, so no connection is required if high-side and low-side outputs are to be controlled by IN+/IN inputs. |
| 3 | DIS | DISable input. Logic level input that when taken high sets all four outputs low. DIS high overrides all other inputs When DIS is taken low the outputs are controlled by the other inputs. The pin can be driven by signal levels of 0V to 15V (no greater than V_{DD}). An internal $100\mu A$ pull-up to V_{DD} will hold DIS high if this pin is not driven. |
| 4 | V_{SS} | Chip negative supply, generally will be ground. |
| 5 | OUT | OUTput of the input control comparator. This output can be used for feedback and hysteresis. |
| 6 | IN+ | Non-inverting input of control comparator. If IN+ is greater than IN- (Pin 7) then ALO and BHO are low leve outputs and BLO and AHO are high level outputs. If IN+ is less than IN- then ALO and BHO are high level outputs and BLO and AHO are low level outputs. DIS (Pin 3) high level will override IN+/IN- control for all outputs. HEN (Pin 2) low level will override IN+/IN- control of AHO and BHO. When switching in four quadrant mode dead time in a half bridge leg is controlled by HDEL and LDEL (Pins 8 and 9). |
| 7 | IN- | Inverting input of control comparator. See IN+ (Pin 6) description. |
| 8 | HDEL | High-side turn-on DELay. Connect resistor from this pin to V_{SS} to set timing current that defines the turn-on delay of both high-side drivers. The low-side drivers turn-off with no adjustable delay, so the HDEL resistor guarantees no shoot-through by delaying the turn-on of the high-side drivers. HDEL reference voltage is approximately 5.1V |
| 9 | LDEL | Low-side turn-on DELay. Connect resistor from this pin to V _{SS} to set timing current that defines the turn-on delay of both low-side drivers. The high-side drivers turn-off with no adjustable delay, so the LDEL resistor guarantees no shoot-through by delaying the turn-on of the low-side drivers. LDEL reference voltage is approximately 5.1V |
| 10 | АНВ | A High-side Bootstrap supply. External bootstrap diode and capacitor are required. Connect cathode of bootstrap diode and positive side of bootstrap capacitor to this pin. Internal charge pump supplies 30µA out of this pin to maintain bootstrap supply. Internal circuitry clamps the bootstrap supply to approximately 12.8V. |
| 11 | AHO | A High-side Output. Connect to gate of A High-side power MOSFET. |
| 12 | AHS | A High-side Source connection. Connect to source of A High-side power MOSFET. Connect negative side of bootstrap capacitor to this pin. |
| 13 | ALO | A Low-side Output. Connect to gate of A Low-side power MOSFET. |
| 14 | ALS | A Low-side Source connection. Connect to source of A Low-side power MOSFET. |
| 15 | V _{CC} | Positive supply to gate drivers. Must be same potential as V _{DD} (Pin 16). Connect to anodes of two bootstrap diodes. |
| 16 | V _{DD} | Positive supply to lower gate drivers. Must be same potential as V _{CC} (Pin 15). De-couple this pin to V _{SS} (Pin 4). |
| 17 | BLS | B Low-side Source connection. Connect to source of B Low-side power MOSFET. |
| 18 | BLO | B Low-side Output. Connect to gate of B Low-side power MOSFET. |
| 19 | BHS | B High-side Source connection. Connect to source of B High-side power MOSFET. Connect negative side o bootstrap capacitor to this pin. |
| 20 | ВНО | B High-side Output. Connect to gate of B High-side power MOSFET. |



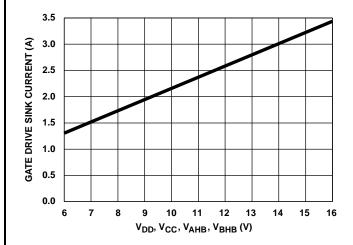








Typical Performance Curves $V_{DD} = V_{CC} = V_{AHB} = V_{BHB} = 12V$, $V_{SS} = V_{ALS} = V_{BLS} = V_{AHS} = V_{BHS} = 0V$, $R_{HDEL} = R_{LDEL} = 100K$, and $T_A = 25^{\circ}C$, Unless Otherwise Specified (Continued)



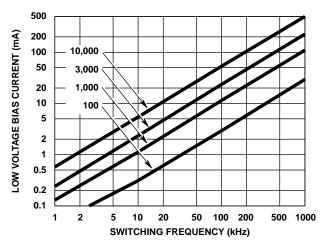
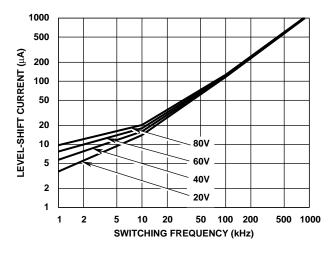


FIGURE 28. PEAK PULLUP CURRENT I_{O+} vs SUPPLY VOLTAGE

FIGURE 29. LOW VOLTAGE BIAS CURRENT I_{DD} AND I_{CC}
(LESS QUIESCENT COMPONENT) vs
FREQUENCY AND GATE LOAD CAPACITANCE



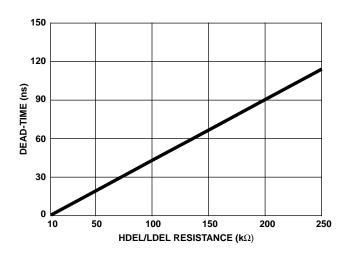


FIGURE 30. HIGH VOLTAGE LEVEL-SHIFT CURRENT vs FREQUENCY AND BUS VOLTAGE

FIGURE 31. MINIMUM DEAD-TIME vs DEL RESISTANCE

HIP4080 Power-up Application Information

The HIP4080 H-Bridge Driver IC requires external circuitry to assure reliable start-up conditions of the upper drivers. If not addressed in the application, the H-Bridge power MOS-FETs may be exposed to shoot-through current, possibly leading to MOSFET failure. Following the instructions below will result in reliable start-up.

The HIP4080 does not have an input protocol like the HIP4081 that keeps both lower power MOSFETs off other than through the DIS pin. IN+ and IN- are inputs to a comparator that control the bridge in such a way that only one of the lower power devices is on at a time, assuming DIS is low. However, keeping both lower MOSFETs off can be accom-

plished by controlling the lower turn-on delay pin, LDEL, while the chip is enabled, as shown in Figure 32. Pulling LDEL to $V_{\rm DD}$ will indefinitely delay the lower turn-on delays through the input comparator and will keep the lower MOSFETs off. With the lower MOSFETs off and the chip enabled, i.e. DIS = low, IN+ or IN- can be switched through a full cycle, properly setting the upper driver outputs. Once this is accomplished, LDEL is released to its normal operating point. It is critical that IN+/IN- switch a full cycle while LDEL is held high, to avoid shoot-through. This start-up procedure can be initiated by the supply voltage and/or the chip enable command by the circuit in Figure 32.

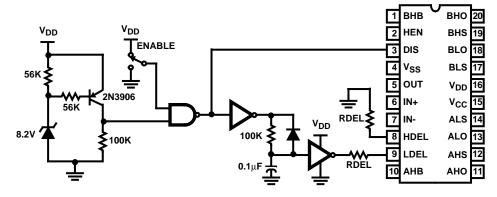
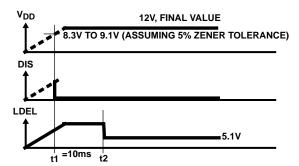


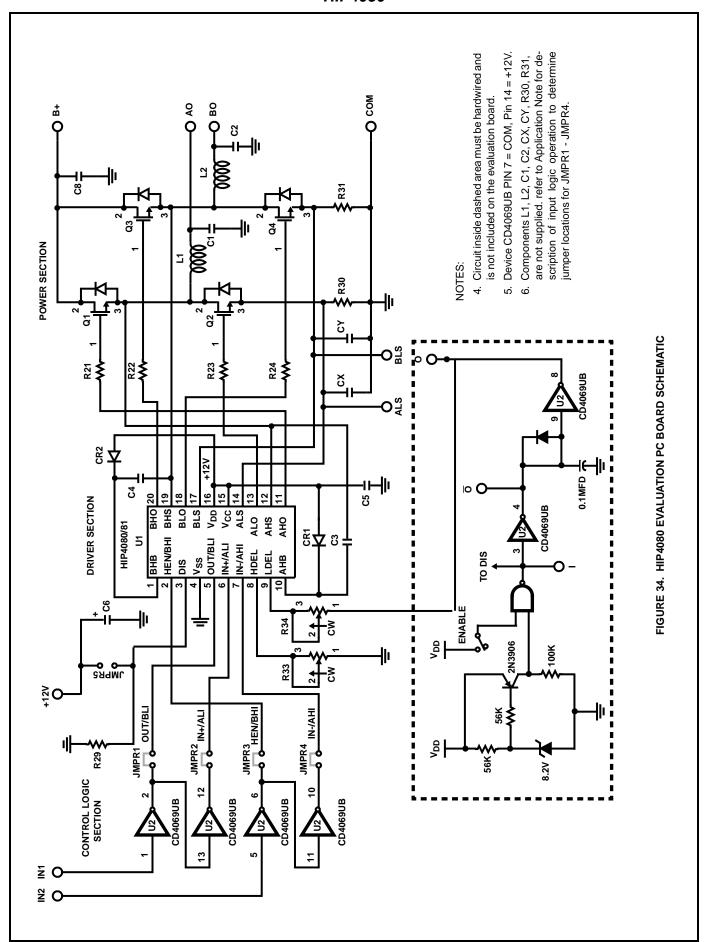
FIGURE 32.



NOTES:

- 2. Between t1 and t2 the IN+ and IN- inputs must cause the OUT pin to go through one complete cycle (transition order is not important). If the ENABLE pin is low after the under-voltage circuit is satisfied, the ENABLE pin will initiate the 10ms time delay during which the IN+ and IN- pins must cycle at least once.
- 3. Another product, HIP4080A, incorporates undervoltage circuitry which eliminates the need for the above power up circuitry.

FIGURE 33. TIMING DIAGRAM FOR FIGURE 32



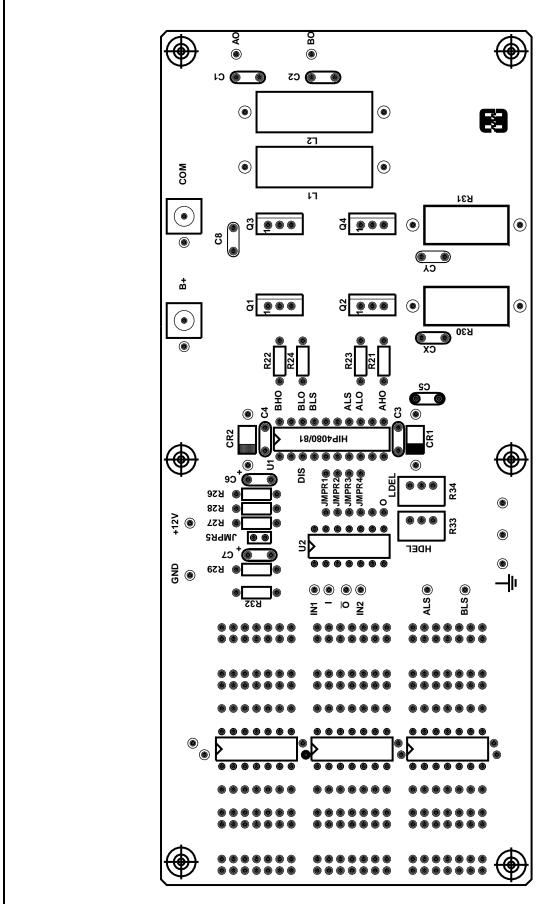


FIGURE 35. HIP4080 EVALUATION BOARD SILKSCREEN

Supplemental Information for HIP4080 and HIP4081 Power-Up Application

The HIP4080 and HIP4081 H-Bridge Driver ICs require external circuitry to assure reliable start-up conditions of the upper drivers. If not addressed in the application, the H-bridge power MOSFETs may be exposed to shoot-through current, possibly leading to MOSFET failure. Following the instructions below will result in reliable start-up.

HIP4081

The HIP4081 has four inputs, one for each output. Outputs ALO and BLO are directly controlled by input ALI and BLI. By holding ALI and BLI low during start-up no shoot-through conditions can occur. To set the latches to the upper drivers such that the driver outputs, AHO and BHO, are off, the DIS pin must be toggled from low to high after power is applied. This is accomplished with a simple resistor divider, as shown below in Figure 36. As the $V_{\rm DD}/V_{\rm CC}$ supply ramps from zero up, the DIS voltage is below its input threshold of 1.7V due to the R1/R2 resistor divider. When $V_{\rm DD}/V_{\rm CC}$ exceeds approximately 9V to 10V, DIS becomes greater than the input threshold and the chip disables all outputs. It is critical that ALI and BLI be held low prior to DIS reaching its threshold

level of 1.7V while V_{DD}/V_{CC} is ramping up, so that shoot through is avoided. After power is up the chip can be enabled by the ENABLE signal which pulls the DIS pin low.

HIP4080

The HIP4080 does not have an input protocol like the HIP4081 that keeps both lower power MOSFETs off other than through the DIS pin. IN+ and IN- are inputs to a comparator that control the bridge in such a way that only one of the lower power devices is on at a time, assuming DIS is low. However, keeping both lower MOSFETs off can be accomplished by controlling the lower turn-on delay pin, LDEL, while the chip is enabled, as shown in Figure 37. Pulling LDEL to VDD will indefinitely delay the lower turn-on delays through the input comparator and will keep the lower MOS-FETs off. With the lower MOSFETs off and the chip enabled, i.e., DIS = low, IN+ or IN- can be switched through a full cycle, properly setting the upper driver outputs. Once this is accomplished, LDEL is released to its normal operating point. It is critical that IN+/IN- switch a full cycle while LDEL is held high, to avoid shoot-through. This start-up procedure can be initiated by the supply voltage and/or the chip enable command by the circuit in Figure 37.

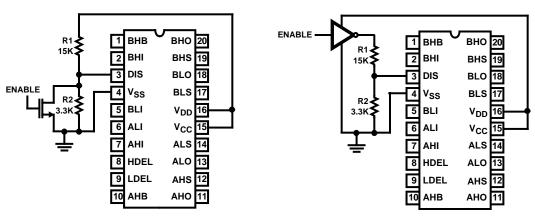
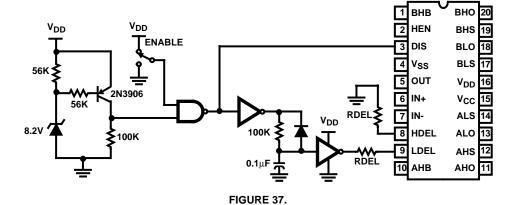
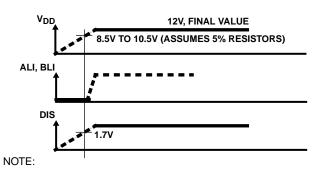


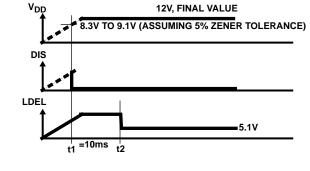
FIGURE 36.



Timing Diagrams



7. ALI and/or BLI may be high after t1, whereupon the ENABLE pin may also be brought high.



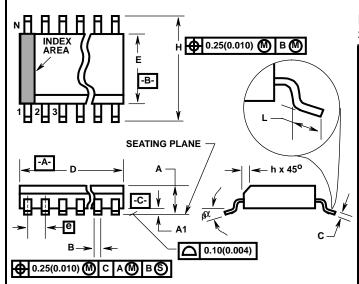
NOTE:

8. Between t1 and t2 the IN+ and IN- inputs must cause the OUT pin to go through one complete cycle (transition order is not important). If the ENABLE pin is low after the undervoltage circuit is satisfied, the ENABLE pin will initiate the 10ms time delay during which the IN+ and IN- pins must cycle at least once.

FIGURE 39.

FIGURE 38.

Small Outline Plastic Packages (SOIC)



NOTES:

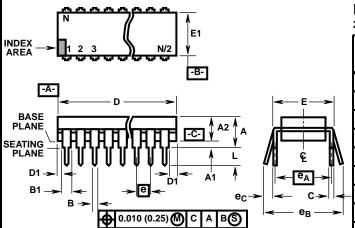
- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M20.3 (JEDEC MS-013-AC ISSUE C)
20 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE

| INCHES MILIMETERS SYMBOL MIN MAX MIN MAX NOTES A 0.0926 0.1043 2.35 2.65 - A1 0.0040 0.0118 0.10 0.30 - B 0.013 0.0200 0.33 0.51 9 C 0.0091 0.0125 0.23 0.32 - D 0.4961 0.5118 12.60 13.00 3 E 0.2914 0.2992 7.40 7.60 4 e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 α 0° 8° - | | | | | | | | | | |
|---|--------|----------------|----------------|--------|----------------|-------|--|--|--|--|
| A 0.0926 0.1043 2.35 2.65 - A1 0.0040 0.0118 0.10 0.30 - B 0.013 0.0200 0.33 0.51 9 C 0.0091 0.0125 0.23 0.32 - D 0.4961 0.5118 12.60 13.00 3 E 0.2914 0.2992 7.40 7.60 4 e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | | INC | HES | MILLIN | IETERS | | | | | |
| A1 0.0040 0.0118 0.10 0.30 - B 0.013 0.0200 0.33 0.51 9 C 0.0091 0.0125 0.23 0.32 - D 0.4961 0.5118 12.60 13.00 3 E 0.2914 0.2992 7.40 7.60 4 e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | SYMBOL | MIN | MAX | MIN | MAX | NOTES | | | | |
| B 0.013 0.0200 0.33 0.51 9 C 0.0091 0.0125 0.23 0.32 - D 0.4961 0.5118 12.60 13.00 3 E 0.2914 0.2992 7.40 7.60 4 e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | Α | 0.0926 | 0.1043 | 2.35 | 2.65 | - | | | | |
| C 0.0091 0.0125 0.23 0.32 - D 0.4961 0.5118 12.60 13.00 3 E 0.2914 0.2992 7.40 7.60 4 e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | A1 | 0.0040 | 0.0118 | 0.10 | 0.30 | - | | | | |
| D 0.4961 0.5118 12.60 13.00 3 E 0.2914 0.2992 7.40 7.60 4 e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | В | 0.013 | 0.0200 | 0.33 | 0.51 | 9 | | | | |
| E 0.2914 0.2992 7.40 7.60 4 e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | С | 0.0091 | 0.0125 | 0.23 | 0.32 | - | | | | |
| e 0.050 BSC 1.27 BSC - H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | D | 0.4961 | 0.5118 | 12.60 | 13.00 | 3 | | | | |
| H 0.394 0.419 10.00 10.65 - h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | Е | 0.2914 | 0.2992 | 7.40 | 7.60 | 4 | | | | |
| h 0.010 0.029 0.25 0.75 5 L 0.016 0.050 0.40 1.27 6 N 20 20 7 | е | 0.050 | BSC | 1.27 | BSC | - | | | | |
| L 0.016 0.050 0.40 1.27 6 N 20 20 7 | Н | 0.394 | 0.419 | 10.00 | 10.65 | - | | | | |
| N 20 20 7 | h | 0.010 | 0.029 | 0.25 | 0.75 | 5 | | | | |
| 20 20 20 20 | L | 0.016 | 0.050 | 0.40 | 1.27 | 6 | | | | |
| α 0° 8° 0° 8° - | N | 2 | 0 | 20 | | 7 | | | | |
| | α | 0 ₀ | 8 ⁰ | 00 | 8 ⁰ | - | | | | |

Rev. 0 12/93

Dual-In-Line Plastic Packages (PDIP)



NOTES:

- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- 4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- 6. E and eal are measured with the leads constrained to be perpendicular to datum -C-.
- e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- B1 maximum dimensions do not include dambar protrusions.
 Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E20.3 (JEDEC MS-001-AD ISSUE D) 20 LEAD DUAL-IN-LINE PLASTIC PACKAGE

| | INC | HES | MILLIM | ETERS | |
|----------------|-------|-------|--------|----------|-------|
| SYMBOL | MIN | MAX | MIN | MAX | NOTES |
| Α | - | 0.210 | - | 5.33 | 4 |
| A1 | 0.015 | - | 0.39 | - | 4 |
| A2 | 0.115 | 0.195 | 2.93 | 4.95 | - |
| В | 0.014 | 0.022 | 0.356 | 0.558 | - |
| B1 | 0.045 | 0.070 | 1.55 | 1.77 | 8 |
| С | 0.008 | 0.014 | 0.204 | 0.355 | - |
| . D | 0.980 | 1.060 | 24.89 | 26.9 | 5 |
| D1 | 0.005 | - | 0.13 | - | 5 |
| E | 0.300 | 0.325 | 7.62 | 8.25 | 6 |
| E1 | 0.240 | 0.280 | 6.10 | 7.11 | 5 |
| е | 0.100 | BSC | 2.54 | BSC | - |
| e _A | 0.300 | BSC | 7.62 | 7.62 BSC | |
| e _B | - | 0.430 | - | 10.92 | 7 |
| L | 0.115 | 0.150 | 2.93 | 3.81 | 4 |
| N | 2 | 0 | 2 | 0 | 9 |

Rev. 0 12/93

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